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Jong Kyu Kim
Michael R. Krames
Martin Strassburg
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Contents

NOVEL TECHNOLOGIES FOR LED DESIGN AND FABRICATION

POSTER SESSION

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

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1 Micro LED Display
Michael R. Krames, Arkesso, LLC (United States)
Jim R. Bonar, Facebook Technologies, LLC (United States)

2 Novel Electroluminescent Semiconductor Materials and Devices for SSL I
Martin Strassburg, OSRAM Opto Semiconductors GmbH (Germany)

3 LED Applications and Solid-State Lighting
Jong Kyu Kim, Pohang University of Science and Technology (Korea, Republic of)

4 Nanomaterials and Nanostructures for LEDs
Aurelien David, Soraa, Inc. (United States)

5 2D Optoelectronics Materials
Debdeep Jena, Cornell University (United States)

6 LED Manufacturing/Epitaxial Growth
Martin Strassburg, OSRAM Opto Semiconductors GmbH (Germany)

7 Novel Electroluminescent Semiconductor Materials and Devices for SSL II
Soo Min Lee, Veeco Instruments Inc. (United States)

8 Efficiency Challenges in III-Nitride LEDs
Aurelien David, Soraa, Inc. (United States)
Michael R. Krames, Arkesso, LLC (United States)

9 NIR/IR-Emitting LEDs
Changmin Lee, SLD Laser (United States)

10 Light-Based Sensors and Communication
Bernd Witzigmann, University Kassel (Germany)

11 Novel Substrates and UV/DUV LEDs and their Applications
Masafumi Jo, RIKEN Center for Brain Science (Japan)

12 UV/DUV LEDs and Their Applications
Tetsuya Takeuchi, Meijo University (Japan)